

RN4986FE,LF(CB

RN4986FE,LF(CB Information

Now masser.com	RN4986FE,LF(CB Toshiba Semiconductor and Storage Discrete Semiconductor Products Transistors - Bipolar (BJT) - Arrays, Pre-Biased TRANS NPN/PNP PREBIAS 0.1W ES6 SOT-563, SOT-666 For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



RN4986FE,LF(CB Specifications

Manufacturer Part Number	RN4986FE,LF(CB	
Manufacturer	Toshiba Semiconductor and Storage	
Category	Discrete Semiconductor Products	
	Transistors - Bipolar (BJT) - Arrays, Pre-Biased	
Package	SOT-563, SOT-666	
Series	-	
Transistor Type	1 NPN, 1 PNP - Pre-Biased (Dual)	
Current - Collector (Ic) (Max)	100mA	
Voltage - Collector Emitter Breakdown (Max)	50V	
Resistor - Base (R1) (Ohms)	4.7k	
Resistor - Emitter Base (R2) (Ohms)	47k	
DC Current Gain (hFE) (Min) @ Ic, Vce	80 @ 10mA, 5V	
Vce Saturation (Max) @ Ib, Ic	300mV @ 250µA, 5mA	
Current - Collector Cutoff (Max)	500nA	
Frequency - Transition	250MHz, 200MHz	
Power - Max	100mW	
Mounting Type	Surface Mount	
Package / Case	SOT-563, SOT-666	
Supplier Device Package	ES6	
	Report errors?	

RN4986FE,LF(CB Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

RN4986FE,LF(CB Payment Methods



RN4986FE,LF(CB Shipping Methods



If you have any question about RN4986FE,LF(CB, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com